# **Quad 2-Input Multiplexer** with 3-State Outputs

The LSTTL/MSI SN74LS257B and the SN74LS258B are Quad 2-Input Multiplexers with 3-state outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (non-inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable (E<sub>O</sub>) Input, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process For High Speed
- Multiplexer Expansion By Tying Outputs Together
- Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- Special Circuitry Ensures Glitch Free Multiplexing
- ESD > 3500 Volts

## **GUARANTEED OPERATING RANGES**

Symbol	Parameter	Min	Тур	Мах	Unit
VCC	Supply Voltage	4.75	5.0	5.25	V
TA	Operating Ambient Temperature Range	0	25	70	°C
ЮН	Output Current – High			-2.6	mA
IOL	Output Current – Low			24	mA



# ON Semiconductor<sup>™</sup>

http://onsemi.com

LOW POWER SCHOTTKY





SOIC D SUFFIX CASE 751B



SOEIAJ M SUFFIX CASE 966

### **ORDERING INFORMATION**

Device	Package	Shipping
SN74LS257BN	16 Pin DIP	2000 Units/Box
SN74LS257BD	SOIC-16	38 Units/Rail
SN74LS257BDR2	SOIC-16	2500/Tape & Reel
SN74LS257BM	SOEIAJ-16	See Note 1
SN74LS257BMEL	SOEIAJ-16	See Note 1
SN74LS258BN	16 Pin DIP	2000 Units/Box
SN74LS258BD	SOIC-16	38 Units/Rail
SN74LS258BDR2	SOIC-16	2500/Tape & Reel
SN74LS258BM	SOEIAJ-16	See Note 1
SN74LS258BMEL	SOEIAJ–16	See Note 1

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

# CONNECTION DIAGRAM DIP (TOP VIEW)



## LOGIC DIAGRAMS



### FUNCTIONAL DESCRIPTION

The LS257B and LS258B are Quad 2-Input Multiplexers with 3-state outputs. They select four bits of data from two sources each under control of a Common Data Select Input. When the Select Input is LOW, the I<sub>0</sub> inputs are selected and when Select is HIGH, the I<sub>1</sub> inputs are selected. The data on the selected inputs appears at the outputs in true (non-inverted) form for the LS257B and in the inverted form for the LS258B.

The LS257B and LS258B are the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select Input. The logic equations for the outputs are shown below:

#### LS257B

 $\underline{Z}_{a} = \underline{E}_{0} \bullet (I_{1a} \bullet S + I_{0a} \bullet \underline{S}) \underline{Z}_{b} = \underline{E}_{0} \bullet (I_{1b} \bullet S + I_{0b} \bullet \underline{S})$  $Z_{c} = E_{0} \bullet (I_{1c} \bullet S + I_{0c} \bullet S) Z_{d} = E_{0} \bullet (I_{1d} \bullet S + I_{0d} \bullet S)$ 

When the Output Enable Input  $(E_0)$  is HIGH, the outputs are forced to a high impedance "off" state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so there is no overlap.

#### LS258B

$\underline{Z}_a = \underline{E}_0 \bullet (I_{1a})$	• S + I <sub>0a</sub>	• <u>S</u> ) <u>Z</u> b =	<u>E</u> 0 • (I <sub>1b</sub> •	• S + I <sub>0b</sub> •	<u>S</u> )
$Z_{\rm C} = E_0 \bullet (I_{\rm 1C})$					

TRUTH TABLE
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OUTPUT ENABLE	SELECT INPUT	DATA INPUTS						OUTPUTS LS257B	OUTPUTS LS258B
EO	s	I <sub>0</sub>	I <sub>1</sub>	Z	Z				
Н	Х	Х	Х	(Z)	(Z)				
L	Н	Х	L	L	Н				
L	Н	Х	Н	н	L				
L	L	L	Х	L	Н				
L	L	Н	Х	Н	L				

H = HIGH Voltage Level

L = LOW Voltage Level X = Don't Care

(Z) = High Impedance (off)

			Limits						
Symbol	Parameter		Min Typ Max		Unit	Tes	t Conditions		
VIH	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
VIL	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs		
VIK	Input Clamp Diode Voltage			-0.65	-1.5	V	V <sub>CC</sub> = MIN, I <sub>IN</sub> =	= –18 mA	
VOH	Output HIGH Voltage		2.4	3.1		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V <sub>IL</sub> per Truth Table		
				0.25	0.4	V	$I_{OL} = 12 \text{ mA}$ $V_{CC} = V_{CC} \text{ MIN},$		
VOL	Output LOW Voltage			0.35	0.5	V	I <sub>OL</sub> = 24 mA	VIN = VIL or VIH per Truth Table	
IOZH	Output Off Current — HIGH	1			20	μΑ	V <sub>CC</sub> = MAX, V <sub>OUT</sub> = 2.7 V		
IOZL	Output Off Current — LOW	1			-20	μΑ	V <sub>CC</sub> = MAX, V <sub>OUT</sub> = 0.4 V		
Чн	Input HIGH Current Other Inputs S Inputs				20 40	μΑ	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 2.7 V		
	Other Inputs S Inputs				0.1 0.2	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 7.0 V		
۱ <sub>IL</sub>	Input LOW Current All Inputs				-0.4	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 0.4 V		
IOS	Short Circuit Current (Note	2)	-30		-130	mA	V <sub>CC</sub> = MAX		
	Power Supply Current Total, Output HIGH	LS257B LS258B			10 9.0	mA			
ICC	Total, Output LOW	LS257B LS258B			16 14	mA	V <sub>CC</sub> = MAX		
	Total, Output 3-State	LS257B LS258B			19 16	mA			

## DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

2. Not more than one output should be shorted at a time, nor for more than 1 second.

# AC CHARACTERISTICS (T\_A = 25°C, V\_{CC} = 5.0 V) See SN74LS251 for Waveforms

		Limits					
Symbol	Parameter	Min Typ Max		Unit	Test Conditions		
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay, Data to Output		10 12	13 15	ns	Figures 1 & 2	Ci – 45 pE
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay, Select to Output		14 14	21 21	ns	Figures 1 & 2	С <sub>L</sub> = 45 рF
<sup>t</sup> PZH	Output Enable Time to HIGH Level		20	25	ns	Figures 4 & 5	C <sub>L</sub> = 45 pF
<sup>t</sup> PZL	Output Enable Time to LOW Level		20	25	ns	Figures 3 & 5	R <sub>L</sub> = 667 Ω
<sup>t</sup> PLZ	Output Disable Time to LOW Level		16	25	ns	Figures 3 & 5	C <sub>L</sub> = 5.0 pF
<sup>t</sup> PHZ	Output Disable Time from HIGH Level		18	25	ns	Figures 4 & 5	R <sub>L</sub> = 667 Ω

# PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
ſ	0.008	0.015	0.21	0.38	
κ	0.110	0.130	2.80	3.30	
Г	0.295	0.305	7.50	7.74	
Μ	0°	10 °	0 °	10 °	
s	0.020	0.040	0.51	1.01	

# PACKAGE DIMENSIONS



NOTES:

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
К	0.10	0.25	0.004	0.009
М	0 °	7°	0°	7°
Ρ	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

#### PACKAGE DIMENSIONS

**M SUFFIX** SOEIAJ PACKAGE CASE 966-01 ISSUE O



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0.10 (0.004)

0.13 (0.005) M

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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2
- CONTROLLING DIMENSION: MILLIMETER. DIMENSIONS D AND E DO NOT INCLUDE MOLD 3. FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006)
- PER SIDE TERMINAL NUMBERS ARE SHOWN FOR 4.
- REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT 5. INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018)

	MILLIN	IETERS	INC	HES			
DIM	MIN	MIN MAX		MAX			
Α		2.05		0.081			
A <sub>1</sub>	0.05	0.20	0.002	0.008			
b	0.35	0.50	0.014	0.020			
C	0.18	0.27	0.007	0.011			
D	9.90	10.50	0.390	0.413			
Е	5.10	5.45	0.201	0.215			
е	1.27	BSC	0.050 BSC				
HE	7.40	8.20	0.291	0.323			
L	0.50	0.85	0.020	0.033			
LE	1.10	1.50	0.043	0.059			
M	0 °	10 °	0 °	10 °			
Q <sub>1</sub>	0.70	0.90	0.028	0.035			
Z		0.78		0.031			

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